60°



August 1997

## LM833

## **Dual Audio Operational Amplifier**

## **General Description**

The LM833 is a dual general purpose operational amplifier designed with particular emphasis on performance in audio systems.

This dual amplifier IC utilizes new circuit and processing techniques to deliver low noise, high speed and wide bandwidth without increasing external components or decreasing stability. The LM833 is internally compensated for all closed loop gains and is therefore optimized for all preamp and high level stages in PCM and HiFi systems.

The LM833 is pin-for-pin compatible with industry standard dual operational amplifiers.

#### **Features**

■ Wide dynamic range: 140dB

■ Low input noise voltage: 4.5nV/√Hz

■ High slew rate: 7 V/µs (typ); 5V/µs (min)

■ High gain bandwidth: 15MHz (typ); 10MHz (min)

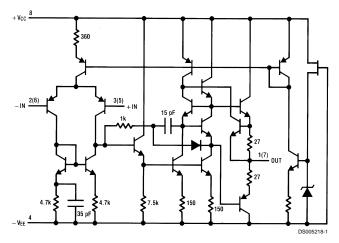
Wide power bandwidth: 120KHzLow distortion: 0.002%

■ Low offset voltage: 0.3mV

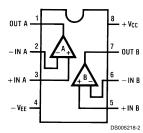
■ Large phase margin:

■ Available in 8 pin MSOP package

## Schematic Diagram (1/2 LM833)



## **Connection Diagram**



Order Number LM833M, LM833N or LM833MM See NS Package Number M08A, N08E or MUA08A

## **Absolute Maximum Ratings** (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage  $V_{CC}$ - $V_{EE}$ 36V ±30V Differential Input Voltage (Note 3) V<sub>I</sub> Input Voltage Range (Note 3) V<sub>IC</sub> ±15V Power Dissipation (Note 4) P<sub>D</sub> 500 mW Operating Temperature Range T<sub>OPR</sub> −40 ~ 85°C Storage Temperature Range T<sub>STG</sub>  $-60 \sim 150^{\circ}C$ 

Soldering Information

Dual-In-Line Package Soldering (10 seconds) Small Outline Package (SOIC and MSOP)

Vapor Phase (60 seconds) Infrared (15 seconds)

215°C 220°C

260°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

1600V ESD tolerance (Note 5)

### DC Electrical Characteristics (Notes 1, 2)

 $(T_A = 25^{\circ}C, V_S = \pm 15V)$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Vos	Input Offset Voltage	$R_S = 10\Omega$		0.3	5	mV
Ios	Input Offset Current			10	200	nA
I <sub>B</sub>	Input Bias Current			500	1000	nA
A <sub>V</sub>	Voltage Gain	$R_{L} = 2 k\Omega, V_{O} = \pm 10V$	90	110		dB
V <sub>OM</sub>	Output Voltage Swing	$R_L = 10 \text{ k}\Omega$	±12	±13.5		V
		$R_L = 2 k\Omega$	±10	±13.4		V
V <sub>CM</sub>	Input Common-Mode Range		±12	±14.0		V
CMRR	Common-Mode Rejection Ratio	V <sub>IN</sub> = ±12V	80	100		dB
PSRR	Power Supply Rejection Ratio	V <sub>S</sub> = 15 ~ 5V, −15 ~ −5V	80	100		dB
IQ	Supply Current	V <sub>O</sub> = 0V, Both Amps		5	8	mA

#### **AC Electrical Characteristics**

 $(T_A = 25^{\circ}C, V_S = \pm 15V, R_L = 2 \text{ k}\Omega)$ 

Symbol Parameter		Conditions	Min	Тур	Max	Units
SR	Slew Rate	$R_L = 2 k\Omega$	5	7		V/µs
GBW	Gain Bandwidth Product	f = 100 kHz	10	15		MHz

## **Design Electrical Characteristics**

 $(T_A = 25^{\circ}C, V_S = \pm 15V)$ The following parameters are not tested or guaranteed.

Symbol	Parameter	Parameter Conditions		Units
$\Delta V_{OS}/\Delta T$	Average Temperature Coefficient		2	μV/°C
	of Input Offset Voltage			
THD	Distortion	$R_L = 2 k\Omega, f = 20 \sim 20 \text{ kHz}$	0.002	%
		$V_{OUT} = 3 \text{ Vrms}, A_V = 1$		
e <sub>n</sub>	Input Referred Noise Voltage	$R_S = 100\Omega$ , $f = 1 \text{ kHz}$	4.5	nV/√Hz
i <sub>n</sub>	Input Referred Noise Current	f = 1 kHz	0.7	pA/√Hz
PBW	Power Bandwidth	$V_{O} = 27 V_{pp}, R_{L} = 2 k\Omega, THD \le 1\%$	120	kHz
f <sub>U</sub>	Unity Gain Frequency	Open Loop	9	MHz
фм	Phase Margin	Open Loop	60	deg
	Input Referred Cross Talk	f = 20 ~ 20 kHz	-120	dB

www.national.com

## **Design Electrical Characteristics** (Continued)

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

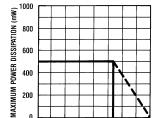
Note 3: If supply voltage is less than ±15V, it is equal to supply voltage.

Note 4: This is the permissible value at  $T_A \le 85^{\circ}C$ .

Note 5: Human body model, 1.5 k $\Omega$  in series with 100 pF.

## **Typical Performance Characteristics**

#### Maximum Power Dissipation vs Ambient Temperature

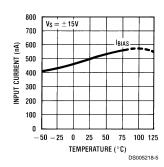


50

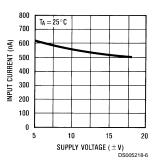
TEMPERATURE (°C)

100

#### Input Bias Current vs Ambient Temperature



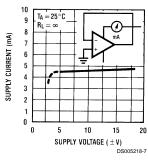
#### Input Bias Current vs Supply Voltage



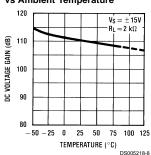
#### Supply Current vs Supply Voltage

0

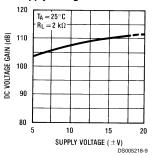
0 L −50



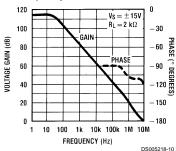
# DC Voltage Gain vs Ambient Temperature



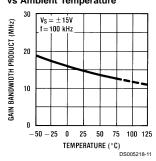
DC Voltage Gain vs Supply Voltage



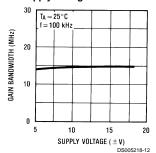
## Voltage Gain & Phase vs Frequency



# Gain Bandwidth Product vs Ambient Temperature

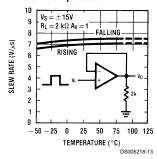


Gain Bandwidth vs Supply Voltage

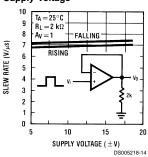


## **Typical Performance Characteristics** (Continued)

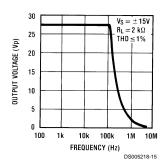
#### Slew Rate vs Ambient Temperature



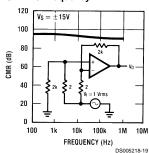
#### Slew Rate vs Supply Voltage



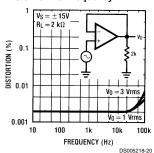
#### **Power Bandwidth**



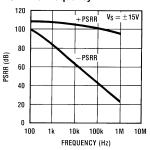
CMR vs Frequency



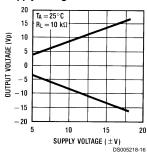
**Distortion vs Frequency** 



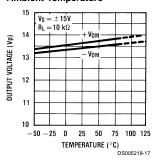
**PSRR** vs Frequency



Maximum Output Voltage vs Supply Voltage

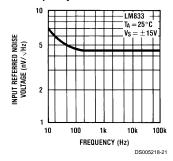


Maximum Output Voltage vs Ambient Temperature

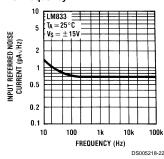


## **Typical Performance Characteristics** (Continued)

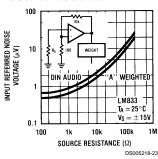
#### Spot Noise Voltage vs Frequency



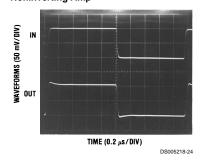
# Spot Noise Current vs Frequency



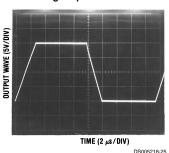
# Input Referred Noise Voltage vs Source Resistance



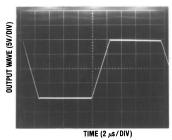
#### **Noninverting Amp**



#### Noninverting Amp



## Inverting Amp



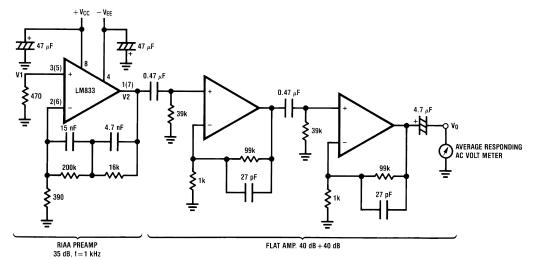
#### DS005218-26

## **Application Hints**

The LM833 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 50 pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 50 pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

## **Noise Measurement Circuit**

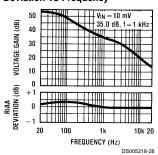


DS005218-27

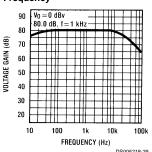
Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

Total Gain: 115 dB @f = 1 kHz Input Referred Noise Voltage:  $e_n$  = V0/560,000 (V)

# RIAA Preamp Voltage Gain, RIAA Deviation vs Frequency

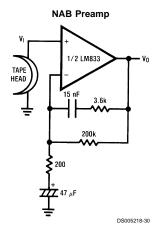


# Flat Amp Voltage Gain vs Frequency



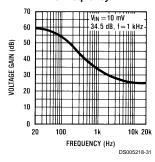
www.national.com

## **Typical Applications**

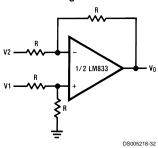


 $A_V = 34.5$  F = 1 kHz  $E_n = 0.38 \mu\text{V}$ A Weighted

# NAB Preamp Voltage Gain vs Frequency

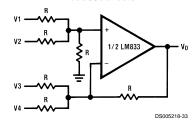


### **Balanced to Single Ended Converter**

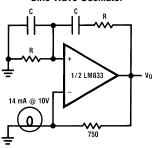


V<sub>O</sub> = V1-V2

### Adder/Subtracter



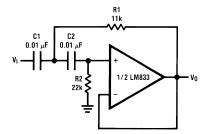
#### Sine Wave Oscillator



DS005218-34

$$f_0 = \frac{1}{2\pi BC}$$

# Second Order High Pass Filter (Butterworth)



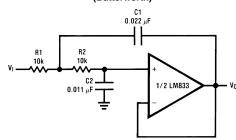
DS005218-35

if C1 = C2 = C

$$R1 = \frac{\sqrt{2}}{2\omega_0 C}$$

Illustration is  $f_0 = 1 \text{ kHz}$ 

# Second Order Low Pass Filter (Butterworth)



DS005218-36

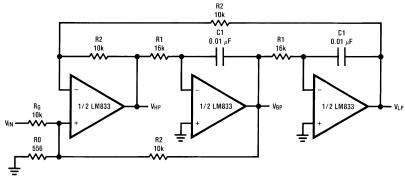
if R1 = R2 = R

$$C1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C2 = \frac{C1}{2}$$

Illustration is  $f_0 = 1 \text{ kHz}$ 

## State Variable Filter

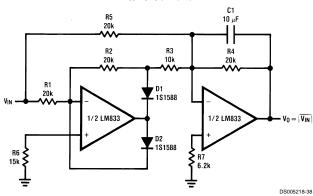


DS005218-37

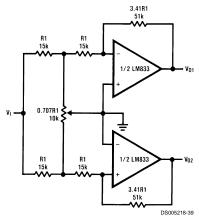
$$f_0 = \frac{1}{2\pi C1R1}, Q = \frac{1}{2} \left( 1 + \frac{R2}{R0} + \frac{R2}{RG} \right), A_{BP} = QA_{LP} = QA_{LH} = \frac{R2}{RG}$$

Illustration is  $f_0 = 1 \text{ kHz}$ , Q = 10,  $A_{BP} = 1$ 

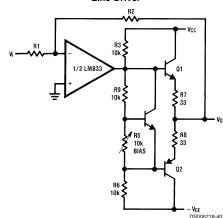
### AC/DC Converter



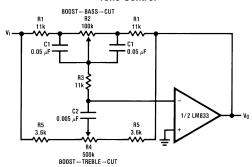
### 2 Channel Panning Circuit (Pan Pot)



#### Line Driver

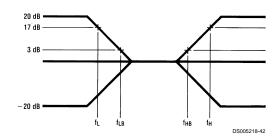


## Tone Control

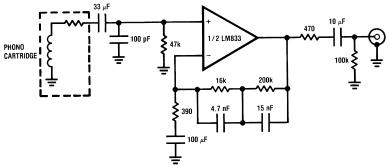


$$\begin{split} f_L &= \frac{1}{2\pi R_2 C_1}, f_{LB} = \frac{1}{2\pi R_1 C_1} \\ f_H &= \frac{1}{2\pi R_2 C_2}, f_{HB} = \frac{1}{2\pi (R_1 + R_2 + 2R_3) C_2} \end{split}$$

#### Illustration is:



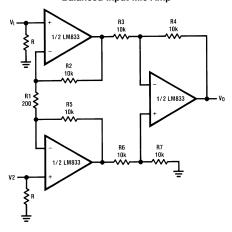
## RIAA Preamp



DS005218-3

$$\begin{aligned} &A_V = 35 \text{ dB} \\ &E_n = 0.33 \text{ } \mu\text{V} \\ &S/N = 90 \text{ dB} \\ &f = 1 \text{ kHz} \\ &A \text{ Weighted}, \\ &A \text{ Weighted}, \\ &V_{IN} = 10 \text{ mV} \end{aligned}$$

## **Balanced Input Mic Amp**



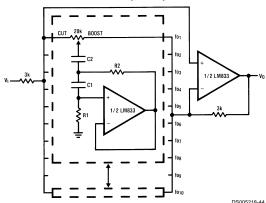
DS005218-43

If R2 = R5, R3 = R6, R4 = R7  

$$V0 = \left(1 + \frac{2R2}{2}\right) \frac{R4}{2} (V2 - V1)$$

Illustration is: V0 = 101(V2 - V1)

## 10 Band Graphic Equalizer



fo(Hz)	C <sub>1</sub>	C <sub>2</sub>	R <sub>1</sub>	R <sub>2</sub>	
32	0.12µF	4.7µF	75kΩ	500Ω	
64	0.056µF	3.3µF	68kΩ	510Ω	
125	0.033µF	1.5µF	62kΩ	510Ω	
250	0.015µF	0.82µF	68kΩ	470Ω	
500	8200pF	0.39µF	62kΩ	470Ω	
1k	3900pF	0.22µF	68kΩ	470Ω	
2k	2000pF	0.1µF	68kΩ	470Ω	
4k	1100pF	0.056µF	62kΩ	470Ω	
8k	510pF	0.022µF	68kΩ	510Ω	
16k	330pF	0.012uF	51kΩ	510Ω	

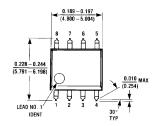
Note 6: At volume of change = ±12 dB

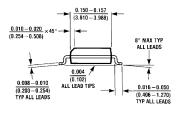
Q = 1.7

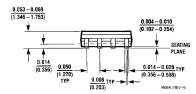
Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2-61

www.national.com 12

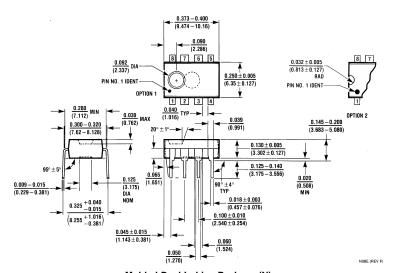
## Physical Dimensions inches (millimeters) unless otherwise noted





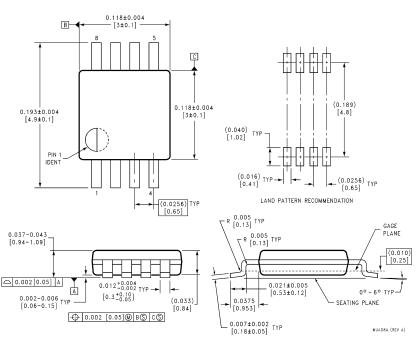


#### Molded Small Outline Package (M) Order Number LM833M NS Package Number M08A



Molded Dual-In-Line Package (N) Order Number LM833N NS Package Number N08E

### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



8-Lead (0.118" Wide) Molded Mini Small Outline Package Order Number LM833MM NS Package Number MUA08A

#### LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DE-VICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMI-CONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation Americas

Tel: 1-800-272-9959 Fax: 1-800-737-7018 Email: support@nsc.com

www.national.com

**National Semiconductor** Europe

Fax: +49 (0) 1 80-530 85 86 Fax: +49 (0) 1 80-530 85 86

Email: europe.support@nsc.com

Deutsch Tel: +49 (0) 1 80-532 85 85

English Tel: +49 (0) 1 80-532 78 32

Français Tel: +49 (0) 1 80-532 93 58

Italiano Tel: +49 (0) 1 80-534 16 80

National Semiconductor Hong Kong Ltd. 13th Floor, Straight Block Ocean Centre, 5 Canton Rd.

Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960 National Semiconductor Japan Ltd. Tel: 81-3-5620-6175 Fax: 81-3-5620-6179